

L Number	Hits	Search Text	DB	Time stamp
-	8	hsg same arsenic and polysilicon and ono and rom	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/11 23:01
-	50	hsg same arsenic and polysilicon and ono and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/11 23:09
-	29	hsg with arsenic and polysilicon and ono and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/11 23:01
-	59	hsg same arsenic and polysilicon and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 15:17
-	1	"6410385".PN.	USPAT	2004/04/12 13:28
-	1	"6154864".PN.	USPAT	2004/04/12 13:29
-	226	hsg and polysilicon and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 17:07
-	1	"09928308"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 16:08
-	1	"6410385".PN.	USPAT	2004/04/12 16:10
-	10	hsg same polysilicon same (ono or "ta.sub.2o.sub.5") same plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 17:20
-	91	hsg same polysilicon same etch\$3 and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 17:23
-	2	hsg with arsenic same polysilicon same etch\$3 and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 17:23
-	5	hsg same arsenic same polysilicon same etch\$3 and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 17:24
-	1	hsg with etch\$3 same arsenic same polysilicon and (ono or "ta.sub.2o.sub.5") and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 17:25
-	242	hemispherical adj grain and polysilicon and ono	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/14 22:23

-	19	hemispherical adj grain and polysilicon and ono and "in situ"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 22:24
-	0	hemispherical adj grain and polysilicon and ono and "in situ" same arsenic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 22:24
-	19	hemispherical adj grain and polysilicon and ono and "in situ"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 22:26
-	85	hemispherical adj grain and polysilicon and ono and arsenic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 22:27
-	85	hemispherical adj grain and polysilicon and ono and arsenic and dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 22:28
-	54	hemispherical adj grain and polysilicon and ono and arsenic and plug	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 22:31
-	39	"5995409" "6134137" "6154864" "6243285" "6410385"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 23:01
-	0	("59954096134137615486462432856410385").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 23:00
-	39	"5995409" "6134137" "6154864" "6243285" "6410385"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 23:20
-	1	"6300191".PN.	USPAT	2004/04/14 23:05
-	1	"6251726".PN.	USPAT	2004/04/14 23:05
-	1	"6221711".PN.	USPAT	2004/04/14 23:05
-	1	"6187624".PN.	USPAT	2004/04/14 23:05
-	1	"6187624".PN.	USPAT	2004/04/14 23:06
-	1	"6140172".PN.	USPAT	2004/04/14 23:06
-	1	"6134137".PN.	USPAT	2004/04/14 23:11
-	1	"6100137".PN.	USPAT	2004/04/14 23:11
-	1	"6046093".PN.	USPAT	2004/04/14 23:11
-	1	"5989952".PN.	USPAT	2004/04/14 23:12
-	0	"6140172" and ono	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/04/14 23:20

-	0	"6140172" and arsenic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/14 23:20
-	69	hsg same arsenic and polysilicon and ono	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/15 15:35
-	11	"6545899"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/15 15:36